

## ES1A - ES1D

#### **Features**

- For surface mount applications.
- Glass passivated junction.
- Low profile package.
- Easy pick and place.
- Built-in strain relief.
- Superfast recovery times for high efficiency.



SMA/DO-214AC COLOR BAND DENOTES CATHODE

## **Fast Rectifiers**

## Absolute Maximum Ratings\* T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter		Va	Units	
		1A	1B	1C	1D
$V_{RRM}$	Maximum Repetitive Reverse Voltage	50 100 150 200		V	
I <sub>F(AV)</sub>	Average Rectified Forward Current, @ T <sub>A</sub> =120°C	1.0			А
I <sub>FSM</sub>	Non-repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave	30		А	
T <sub>stg</sub>	Storage Temperature Range	-50 to +150		°C	
T <sub>J</sub>	Operating Junction Temperature	-50 to +150		°C	

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

## **Thermal Characteristics**

Symbol	Parameter	Value	Units
$P_{D}$	Power Dissipation	1.47	W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient*	85	°C/W
R <sub>eJL</sub>	Thermal Resistance, Junction to Lead*	35	°C/W

<sup>\*</sup>Device mounted on FR-4 PCB 0.013 mm.

## **Electrical Characteristics** T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter		Device				Units
•			1A	1B	1C	1D	
$V_{F}$	Forward Voltage @ 1.0 A			0.9	2		V
t <sub>rr</sub>	Reverse Recovery Time $I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{RR} = 0.25 \text{ A}$			15	5		ns
I <sub>R</sub>	Reverse Current @ rated V <sub>R</sub>	$\Gamma_A = 25^{\circ}C$ $\Gamma_A = 100^{\circ}C$		5.0 10			μΑ μΑ
Ст	Total Capacitance V <sub>R</sub> = 4.0 V, f = 1.0 MHz			7.0	)		pF

## **Typical Characteristics**

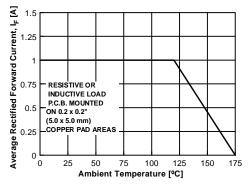
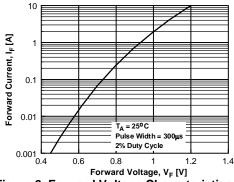


Figure 1. Forward Current Derating Curve



**Figure 2. Forward Voltage Characteristics** 

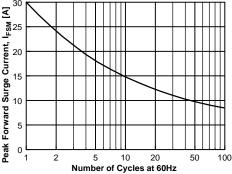


Figure 3. Non-Repetitive Surge Current

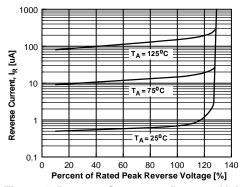


Figure 4. Reverse Current vs Reverse Voltage

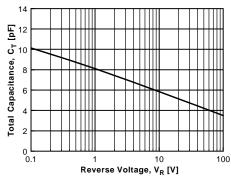
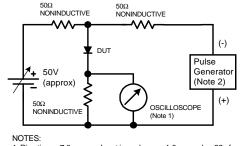
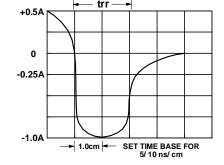


Figure 5. Total Capacitance



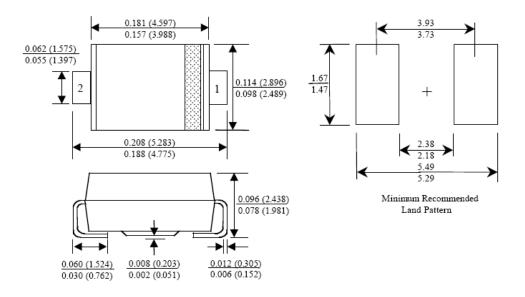
1. Rise time = 7.0 ns max; Input impedance = 1.0 megaohm 22 pf. 2. Rise time = 10 ns max; Source impedance = 50 ohms.



Reverse Recovery Time Characterstic and Test Circuit Diagram

# **Package Dimensions**

# SMA / DO - 214AC



Dimensions in Millimeters

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Rev. H4

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## > Address:

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd Minhang District, Shanghai , China

## > Sales:

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

## Customer Service :

Email service@ameya360.com

# Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com